Silicon P-Channel MOS Type / Silicon Epitaxial Schottky Barrier Diode

SSM5G06FE

DC-DC Converter Applications

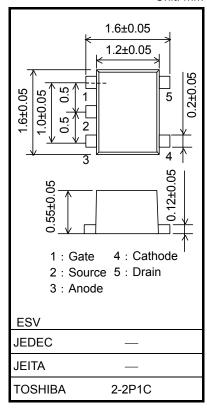
- Combined a P-channel MOSFET and a Schottky barrier diode in one package.
- Optimum for high-density mounting in small packages

Absolute Maximum Ratings (Ta = 25°C) MOSFET

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V _{DSS}	-20	V	
Gate-Source voltage		V _{GSS}	±10	V	
Drain current	DC	I _D	-100	mA	
Drain current	Pulse	I _{DP} (Note 2)	-200		
Power dissipation		P _D (Note 1)	150	mW	
Channel temperature		T _{ch}	150	°C	

Absolute Maximum Ratings (Ta = 25°C) SBD

Characteristics	Symbol	Rating	Unit
Maximum (peak) reverse voltage	V _{RM}	15	V
Reverse voltage	V _R	12	V
Average forward current	Ι _Ο	100	mA
Peak one cycle surge forward current (10ms)	I _{FSM}	1 (50 Hz)	А
Junction temperature	Тj	125	°C



Weight: 3 mg (Typ.)

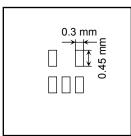
Absolute Maximum Ratings (Ta = 25°C) MOSFET, SBD COMMON

Characteristics	Symbol	Rating	Unit
Storage temperature range	T _{stg}	-55 to 125	°C
Operating temperature range	T _{opr} (Note3)	-40 to 100	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Total rating. Mounted on an FR4 board. (25.4 mm \times 25.4 mm \times 1.6 mm, Cu Pad: 0.135 mm² \times 5)

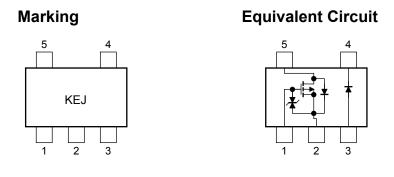


Start of commercial production 2002-08

Unit: mm

Note 2: The pulse width limited by max channel temperature.

Note 3: Operating temperature limited by max channel temperature and max junction temperature.



Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static discharge. Operators should wear anti-static clothing and use containers and other objects that are made of anti-static materials.

MOSFET

Electrical Characteristics (Ta = 25°C)

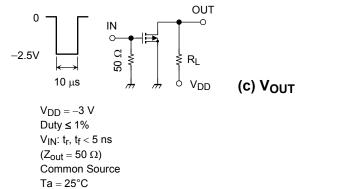
Chara	acteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curr	rent	I _{GSS}	$V_{GS} = \pm 10$ V, $V_{DS} = 0$ V	_		±1	μA
Drain-Source brea	akdown voltage	V (BR) DSS	$I_D = -0.1 \text{ mA}, V_{GS} = 0 \text{ V}$	-20		_	V
Drain Cut-off curre	ent	I _{DSS}	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$	_		-1	μA
Gate threshold vo	Itage	V _{th}	$V_{DS} = -3 \text{ V}, \text{ I}_{D} = -0.1 \text{ mA}$	-0.6		-1.1	V
Forward transfer a	admittance	Y _{fs}	$V_{DS} = -3 V$, $I_D = -10 mA$ (Note 4)	25			mS
Drain-Source on-resistance		R _{DS} (ON)	$I_D = -10 \text{ mA}, V_{GS} = -4 \text{ V}$ (Note 4)	_	6	8	Ω
			$I_D = -10 \text{ mA}, V_{GS} = -2.5 \text{ V}$ (Note 4)	_	8	12	
			$I_D = -1 \text{ mA}, V_{GS} = -1.5 \text{ V}$ (Note 4)	_	18	45	
Input capacitance		C _{iss}	$V_{DS} = -3 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	11		pF
Reverse transfer	capacitance	C _{rss}	$V_{DS} = -3 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	3.7		pF
Output capacitance	ce	C _{oss}	$V_{DS} = -3 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	10		pF
Switching time	Turn-on time	t _{on}	$V_{DD} = -3 V, I_D = -10 mA,$	_	130		
	Turn-off time	t _{off}	$V_{GS} = 0 \text{ to} - 2.5 \text{ V}$	_	190		ns

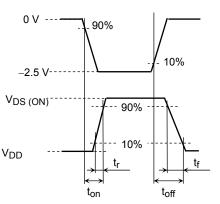
Note 4: Pulse test

Switching Time Test Circuit



(b) V_{IN}





Precaution

 V_{th} can be expressed as voltage between gate and source when low operating current value is I_D = -100 µA for this product. For normal switching operation, $V_{GS (on)}$ requires higher voltage than V_{th} and $V_{GS (off)}$ requires lower voltage than V_{th} .

(Relationship can be established as follows: $V_{GS (off)} < V_{th} < V_{GS (on)}$) Please take this into consideration for using the device.

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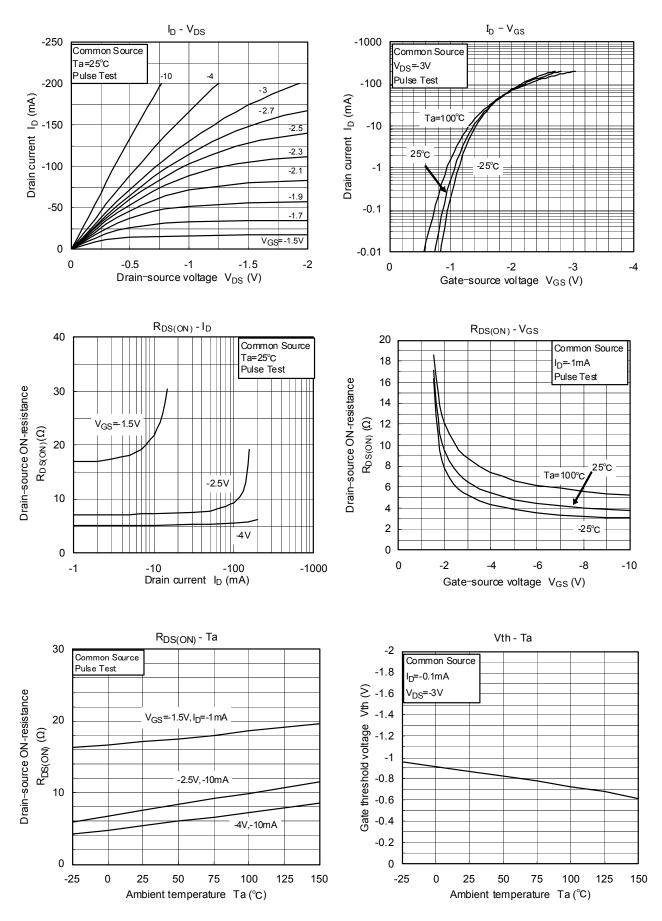
Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward voltage	V _{F (1)}	I _F = 1 mA		0.18	_	V
	V _{F (2)}	$I_F = 5 \text{ mA}$		0.23	0.30	V
	V _{F (3)}	I _F = 100 mA		0.35	0.50	V
Reverse current	I _R	V _R = 12 V	_	_	22	μA
Total capacitance	CT	V _R = 0 V, f = 1 MHz	_	20	40	pF

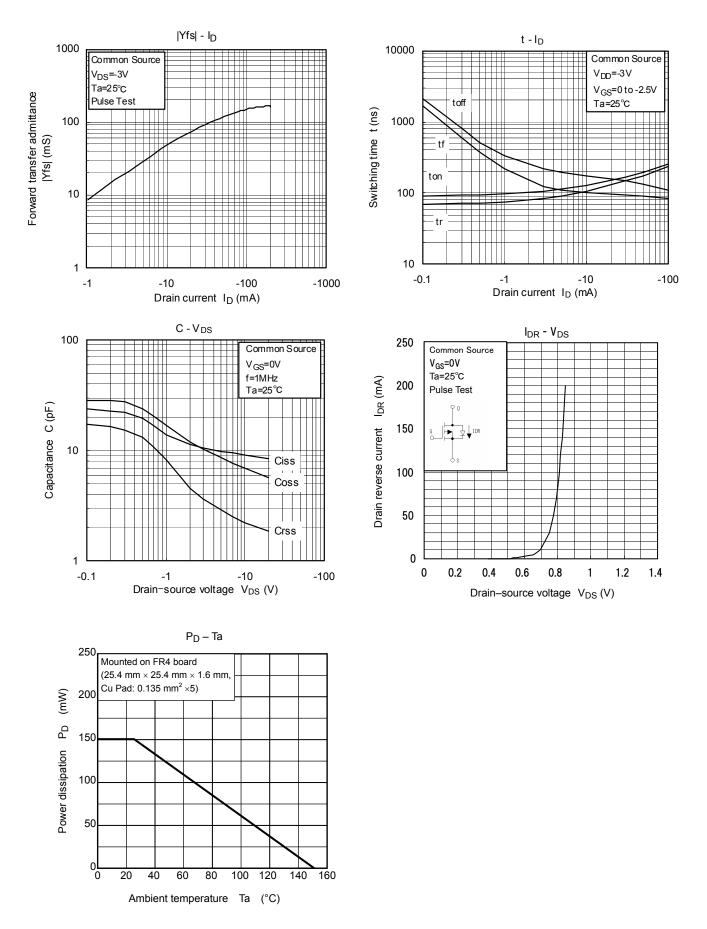
Precaution

The Schottky barrier diode in this device has large reverse current leakage compared to typical switching diodes. Thus, excessive operating temperature or voltage may cause thermal runaway. To avoid this problem, be sure to take both forward and reverse loss into consideration.

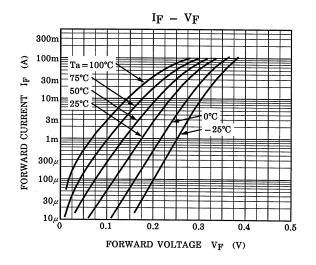
MOSFET

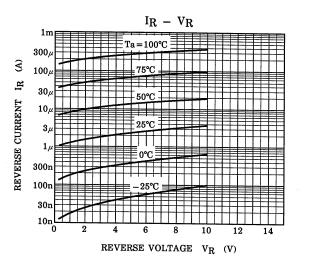


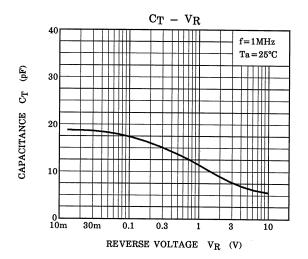
MOSFET



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